

測試報告

號碼(No.): CE/2008/81406

日期(Date): 2008/08/13

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Test Report

FULTEC SEMICONDUCTOR INC

2029 STIERLIN COURT, SUITE 120 MOUNTAIN VIEW, CA 94043

以下測試樣品係由客户送樣, 且由客户聲稱並經客户確認如下 (The following samples was/were submitted and identified by/on behalf of the client as):

樣品名稱(Sample Description)

樣品型號(Style/Item No.) 收件日期(Sample Receiving Date)

測試期間(Testing Period)

: FULTEC TBU

: PX50-GXXX

: 2008/8/6

2008/8/6 TO 2008/8/13

測試需求(Test Requested)

: 參照 RoHS 2002/95/EC 及其修定指令要求. (In accordance with the RoHS Directive 2002/95/EC, and its amendment directives).

測試方法(Test Method)

- : 参考IEC 62321/2nd CDV (111/95/CDV)方法檢測. (With reference to IEC 62321/2nd CDV (111/95/CDV). Procedures for the Determination of Levels of Regulated Substances in Electrotechnical Products).
 - (1) 用感應藕合電漿原子發射光譜儀檢測鎘含量. / Determination of Cadmium by ICP-AES.
 - (2) 用感應藕合電漿原子發射光譜儀檢測鉛含量. / Determination of Lead by ICP-AES.
 - (3) 用感應藕合電漿原子發射光譜儀檢測汞含量. / Determination of Mercury by ICP-AES.
 - (4) 針對非金屬材質之樣品,用UV-VIS檢測六價鉻含量. / Determination of Hexavalent Chromium for non-metallic samples by UV/Vis Spectrometry.
 - (5) 以氣相層析儀/質譜儀檢測多溴聯苯和多溴聯苯醚含量. / Determination of PBB and PBDE by GC/MS.

測試結果(Test Results)

: 請見下一頁 (Please refer to next pages).

Chenyu Kung / Operation Manager Signed for and on behalf of SGS TAIWAN LTD.

Chemical Laboratory - Taipei

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測試結果(Test Results) 單位(Unit): mg/kg

測試項目	測試方法 Method	結果 (Result)	方法偵測 極限値
(Test Items)	(Refer to)	No.1	他DL)
鎬 / Cadmium (Cd)	(1)	n.d.	2
鉛 / Lead (Pb)	(2)	n.d.	2
汞 / Mercury (Hg)	(3)	n.d.	2
六價鉻 / Hexavalent Chromium Cr(VI) by	(4)	n.d.	2
alkaline extraction			
多溴聯苯總和 / Sum of PBBs	(5)	n.d.	-
一溴聯苯 / Monobromobiphenyl		n.d.	5
二溴聯苯 / Dibromobiphenyl		n.d.	5
三溴聯苯 / Tribromobiphenyl		n.d.	5
四溴聯苯 / Tetrabromobiphenyl		n.d.	5
五溴聯苯 / Pentabromobiphenyl		n.d.	5
六溴聯苯 / Hexabromobiphenyl		n.d.	5
七溴聯苯 / Heptabromobiphenyl		n.d.	5
八溴聯苯 / Octabromobiphenyl		n.d.	5
九溴聯苯 / Nonabromobiphenyl		n.d.	5
十溴聯苯 / Decabromobiphenyl		n.d.	5
多溴聯苯醚總和 / Sum of PBDEs		n.d.	-
一溴聯苯醚 / Monobromodiphenyl ether		n.d.	5
二溴聯苯醚 / Dibromodiphenyl ether		n.d.	5
三溴聯苯醚 / Tribromodiphenyl ether		n.d.	5
四溴聯苯醚 / Tetrabromodiphenyl ether		n.d.	5
五溴聯苯醚 / Pentabromodiphenyl ether		n.d.	5
六溴聯苯醚 / Hexabromodiphenyl ether		n.d.	5
七溴聯苯醚 / Heptabromodiphenyl ether		n.d.	5
八溴聯苯醚 / Octabromodiphenyl ether		n.d.	5
九溴聯苯醚 / Nonabromodiphenyl ether		n.d.	5
十溴聯苯醚 / Decabromodiphenyl ether		n.d.	5

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測試部位描述 (TEST PART DESCRIPTION):

NO.1 : 整體混測 (PX-50-GXXX) (MIXED ALL PARTS)

備註(Note):

- 1. mg/kg = ppm
- 2. n.d. = Not Detected (未檢出)
- 3. MDL = Method Detection Limit (方法偵測極限值)
- 4. "-" = Not Regulated (無規格值)
- 5. 樣品的測試是基於申請人要求混合測試,報告中的混合測試結果不代表其中個别單一材質的含量. (The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value).

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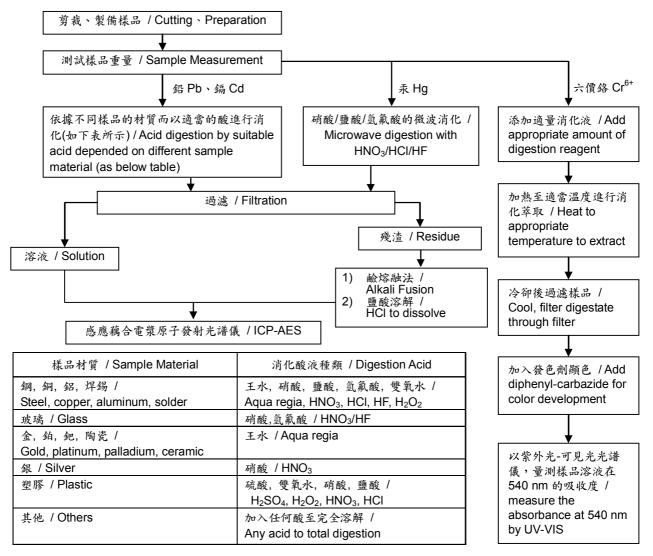
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- 1) 根據以下的流程圖之條件,樣品已完全溶解。(六價鉻測試方法除外) / These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr^{6+} test method excluded)
- 2) 測試人員:楊登偉 / Name of the person who made measurement: Climbgreat Yang
- 3) 測試負責人: 張啓興 / Name of the person in charge of measurement: Troy Chang



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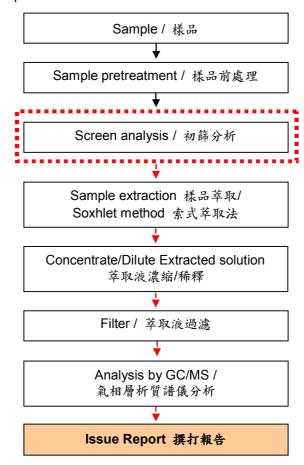
多溴聯苯/多溴聯苯醚分析流程圖 / PBB/PBDE analytical FLOW CHART

- 1) 測試人員: 翁賜彬 / Name of the person who made measurement: Roman Wong
- 2) 測試負責人: 陳新智 / Name of the person in charge of measurement: Shinjyh Chen

初次測試程序 / First testing process ──→

選擇性篩檢程序 / Optional screen process

確認程序 / Confirmation process - · - ▶



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報告結尾 **

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